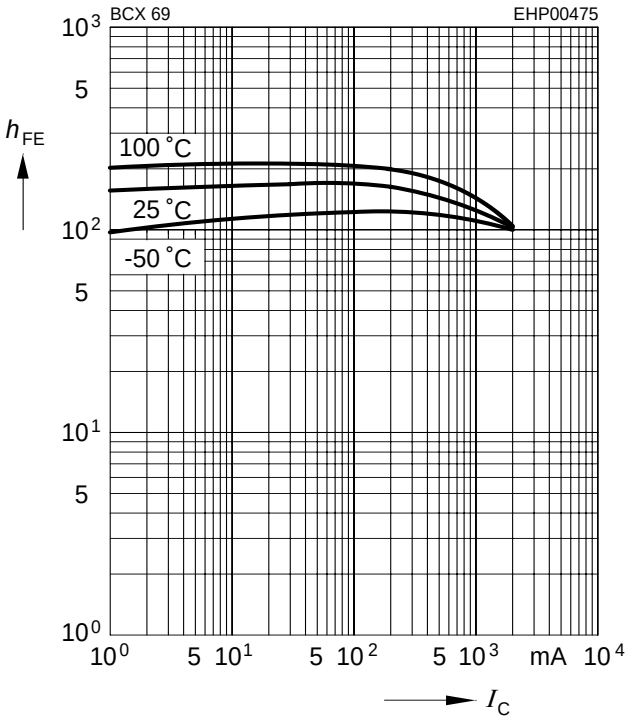
Electrical Characteristics at T_A = 25°C, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					
Collector-emitter breakdown voltage I_C = 30 mA, I_B = 0	$V_{(BR)CEO}$	20	-	-	V
Collector-base breakdown voltage I_C = 10 µA, I_E = 0	$V_{(BR)CBO}$	25	-	-	
Emitter-base breakdown voltage I_E = 1 µA, I_C = 0	$V_{(BR)EBO}$	5	-	-	
Collector-base cutoff current	I_{CBO}				µA
V_{CB} = 25 V, I_E = 0		-	-	0.1	
V_{CB} = 25 V, I_E = 0 , T_A = 150		-	-	100	
DC current gain[1)]	h_{FE}				-
I_C = 5 mA, V_{CE} = 10 V		50	-	-	
I_C = 500 mA, V_{CE} = 1 V, BCX69-10		85	100	160	
I_C = 500 mA, V_{CE} = 1 V, BCX69-16		100	160	250	
I_C = 500 mA, V_{CE} = 1 V, BCX69-25		160	250	375	
I_C = 1 A, V_{CE} = 1 V		60	-	-	
Collector-emitter saturation voltage[1)] I_C = 1 A, I_B = 100 mA	V_{CEsat}	-	-	0.5	V
Base-emitter voltage[1)]	$V_{BE(ON)}$				
I_C = 5 mA, V_{CE} = 10 V		-	0.6	-	
I_C = 1 A, V_{CE} = 1 V		-	-	1	
AC Characteristics					
Transition frequency I_C = 100 mA, V_{CE} = 5 V, f = 20 MHz	f_T	-	100	-	MHz

[1]Pulse test: t < 300µs; D < 2%

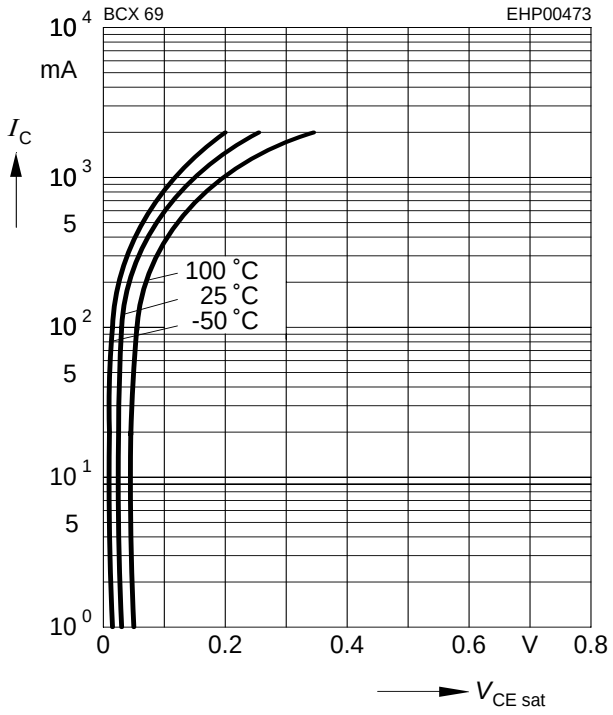
DC current gain $h_{FE} = f(I_C)$

V_{CE} = 1 V



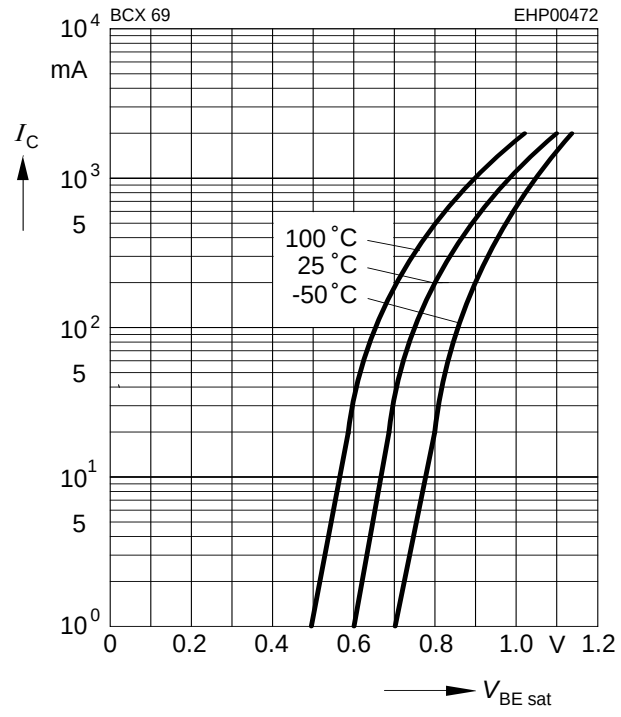
Collector-emitter saturation voltage

$I_C = f(V_{CEsat})$, h_{FE} = 10



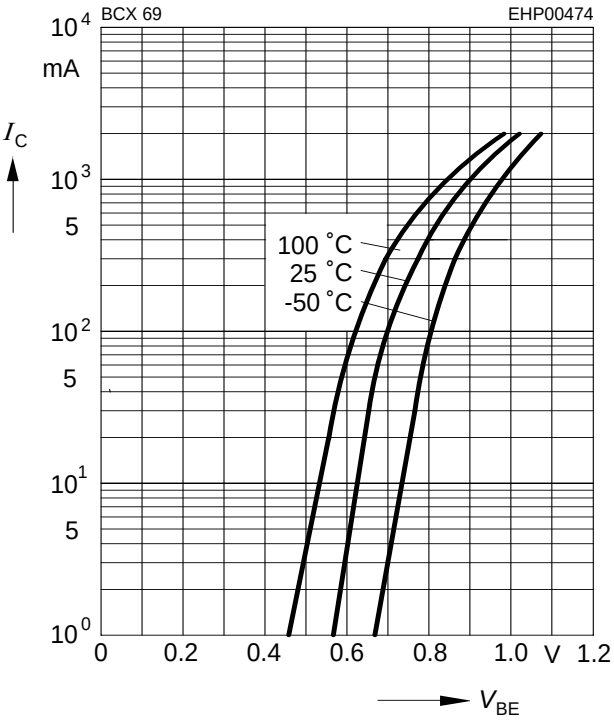
Base-emitter saturation voltage

$I_C = f(V_{BEsat})$, h_{FE} = 10



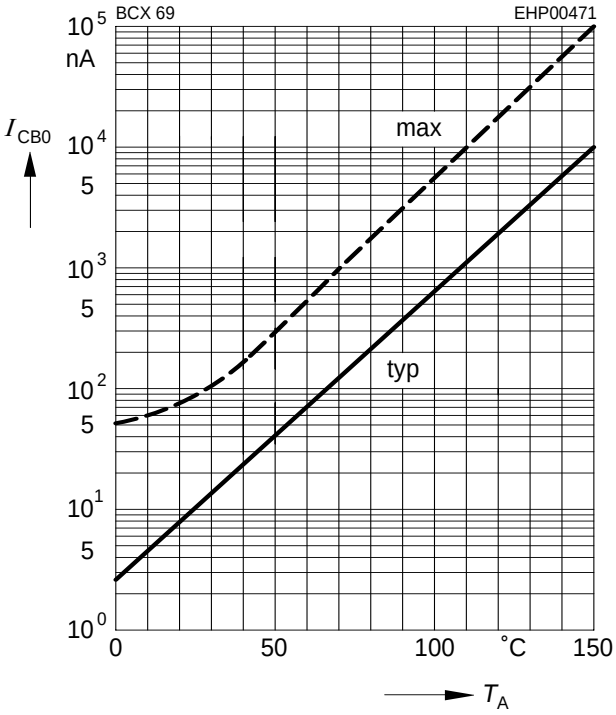
Collector current $I_C = f(V_{BE})$

V_{CE} = 1V



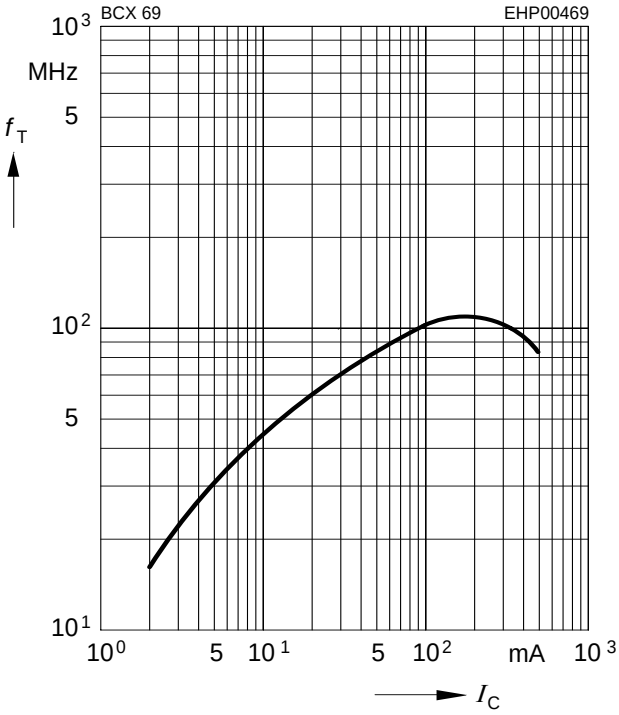
Collector cutoff current I_{CBO} = $f(T_A)$

V_{CB} = 25 V

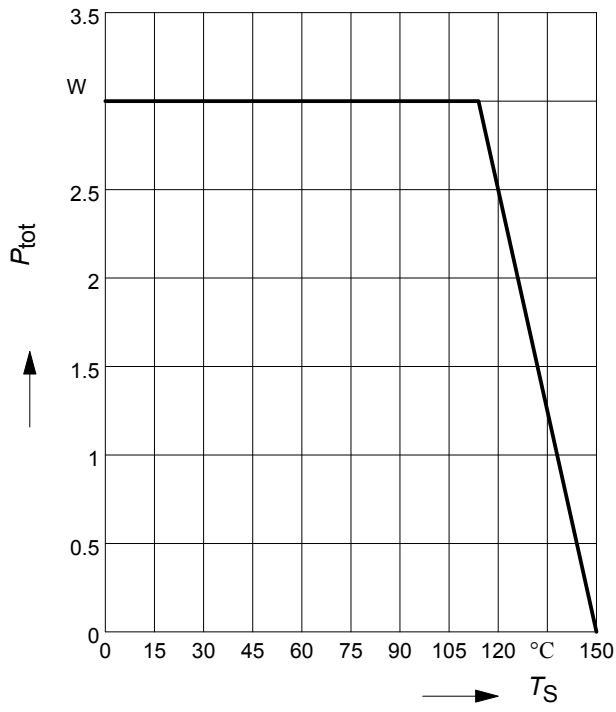


Transition frequency f_T = $f(I_C)$

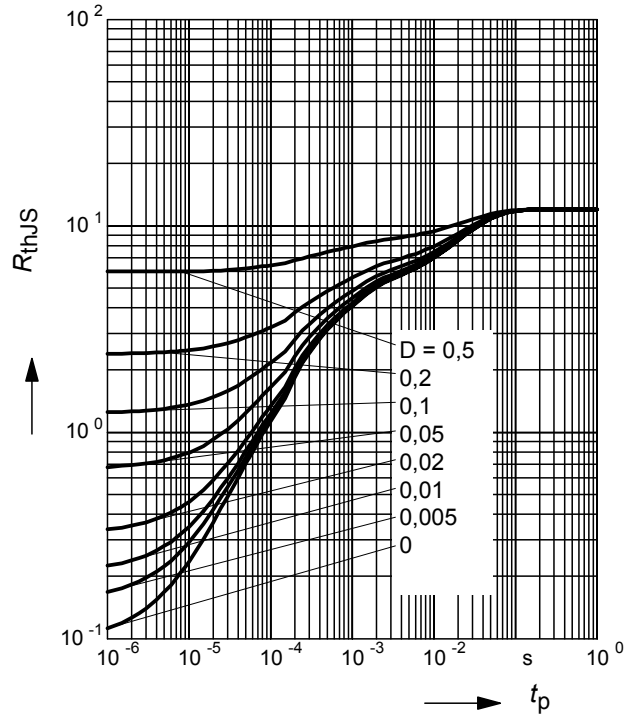
V_{CE} = 5 V



Total power dissipation P_{tot} = $f(T_S)$

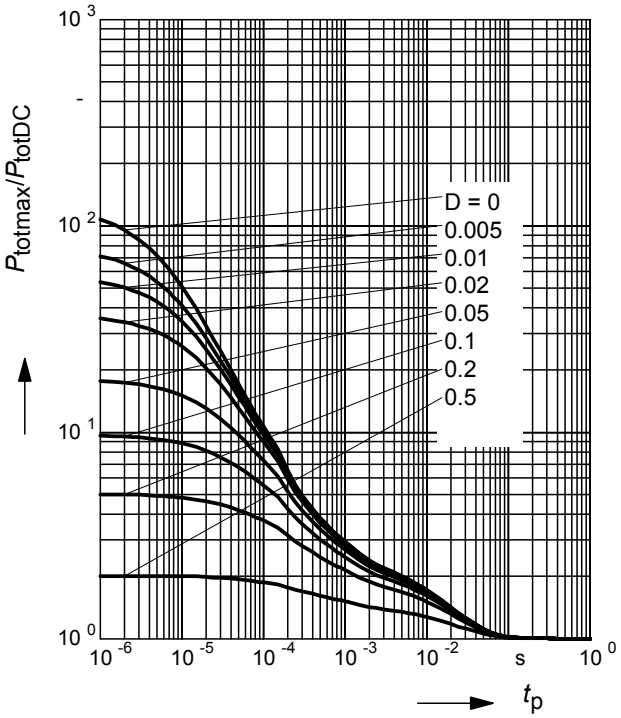


Permissible Pulse Load R_{thJS} = $f(t_p)$

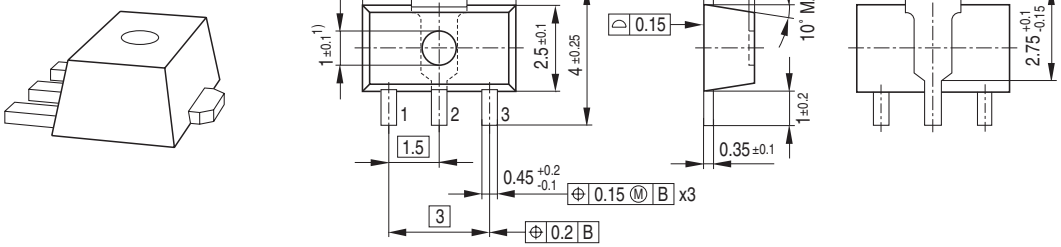


Permissible Pulse Load

$P_{totmax}/P_{totDC} = f(t_p)$

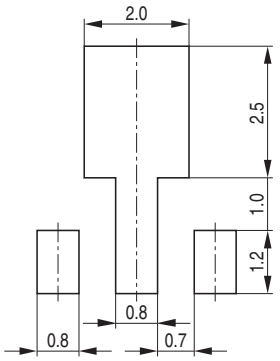


Package Outline

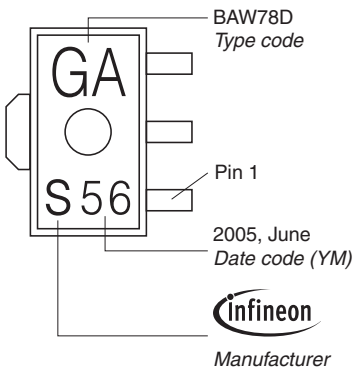


1) Ejector pin markings possible

Foot Print

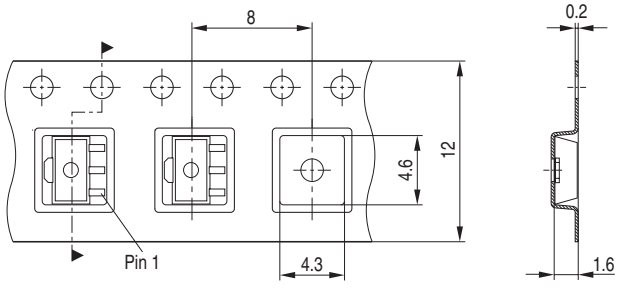


Marking Layout (Example)



Standard Packing

Reel ø180 mm = 1.000 Pieces/Reel
Reel ø330 mm = 4.000 Pieces/Reel



Edition 2009-11-16

Published by
Infineon Technologies AG
81726 Munich, Germany

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